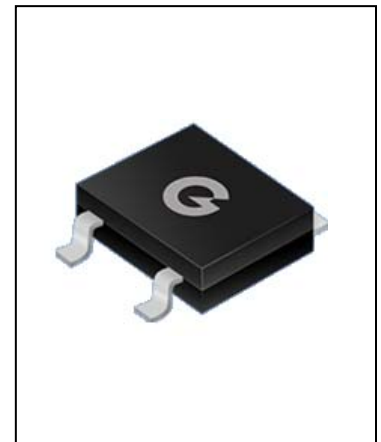


SILICON BRIDGE RECTIFIERS

DB201S--DB207S

FEATURES

- Rating to 1000V PRVP
- Surge overload rating to 30 Amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Lead solderable per MIL-STD-202 method 208
- Glass passivated chip junctions
- Plastic material has UL flammability classification 94V-0
- Polarity symbols molded on body
- Weight: 0.016 ounces, 0.45 grams



Maximum Ratings (@T_A = 25°C unless otherwise specified)

Characteristic	Symbol	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	35	75	140	280	420	560	700	V
DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @T _A =25°C	I _{F(AV)}	2.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	60							A

Thermal Characteristics

Characteristic	Symbol	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	UNITS
Operating junction temperature range	T _J	- 55 ---- + 150							°C
Storage temperature range	T _{STG}	- 55 ---- + 150							°C

Electrical Characteristics (@T_A = 25°C unless otherwise specified)

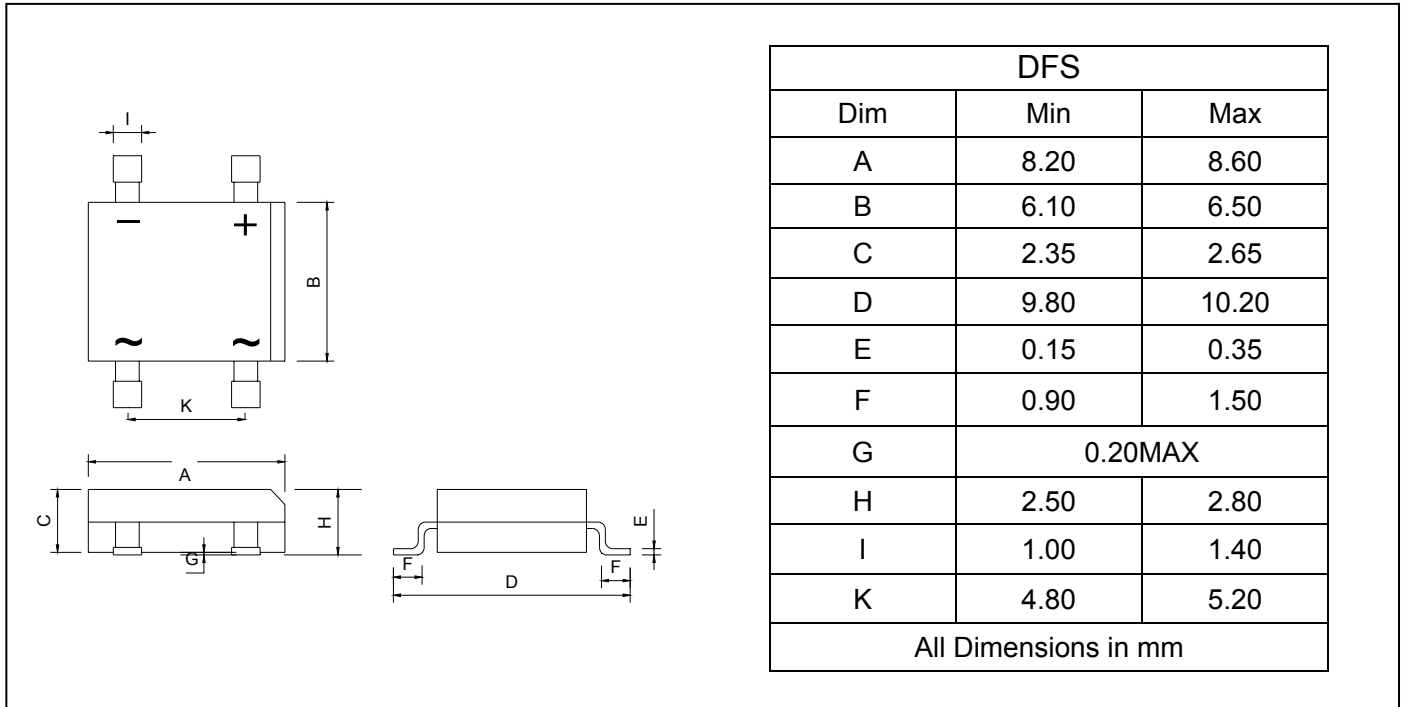
Characteristic	Symbol	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	UNITS
Maximum instantaneous forward voltage at 2.0 A	V _F	1.1							V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 1.0							μ A mA



SILICON BRIDGE RECTIFIERS

DB201S--DB207S

PACKAGE OUTLINE DIMENSIONS



PACKAGE INFORMATION

Device	Package	Shipping
DB201S--DB207S	DFS	50unit/pipe



SILICON BRIDGE RECTIFIERS

DB201S--DB207S

FIG.1 – TYPICAL FORWARD CURRENT DERATING CURVE

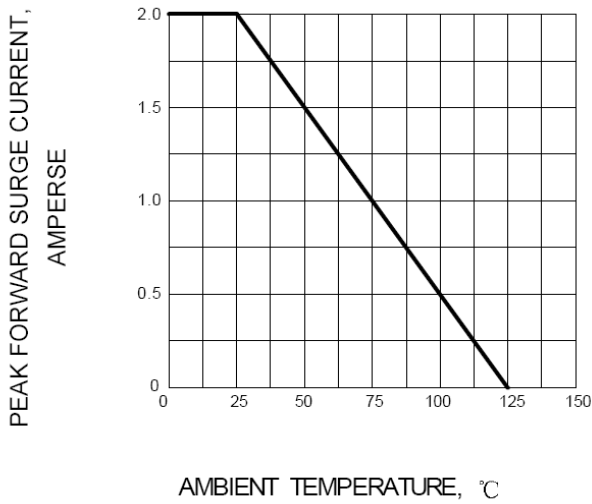


FIG.2 – MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

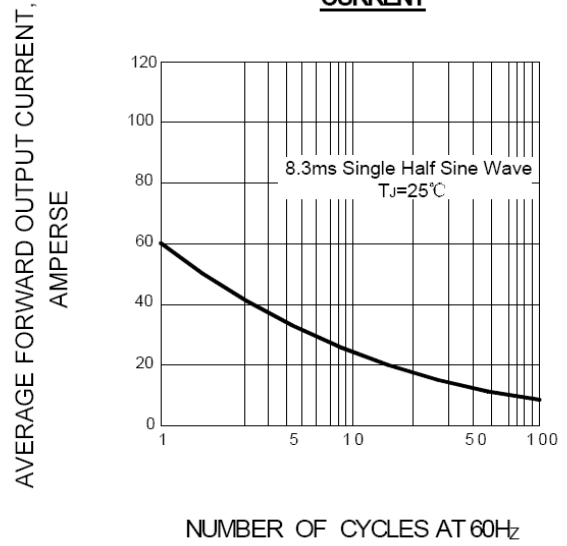


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

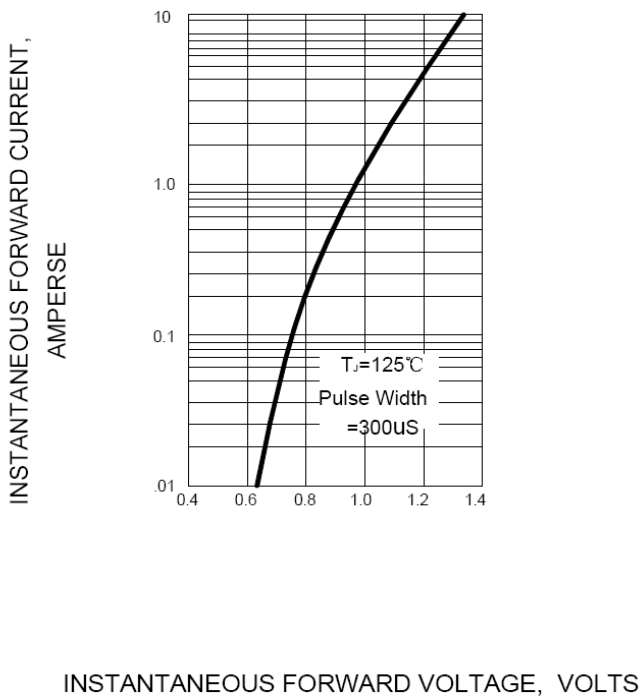


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

